



**10-FZ12NMA080SH04-M260F13**  
**10-PZ12NMA080SH04-M260F13Y**  
datasheet

Vincotech

<b>flowMNPC 0</b>		<b>1200 V / 80 A</b>
<b>Features</b>		
	<ul style="list-style-type: none"><li>• Three-level MNPC (T-Type)</li><li>• Reactive power capability</li><li>• Low inductance layout</li><li>• Improved LVRT</li></ul>	
<b>Target applications</b>		<b>Schematic</b>
	<ul style="list-style-type: none"><li>• Industrial Drives</li><li>• Solar Inverters</li><li>• UPS</li></ul>	
<b>Types</b>		
	<ul style="list-style-type: none"><li>• 10-FZ12NMA080SH04-M260F13</li><li>• 10-PZ12NMA080SH04-M260F13Y</li></ul>	

## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Buck Switch</b>				
Collector-emitter voltage	$V_{CES}$		1200	V
Collector current	$I_C$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	76	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	240	A
Turn off safe operating area		$T_j \leq 175^\circ\text{C}$ , $V_{CE} \leq 1200\text{ V}$	320	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	186	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ $V_{cc} = 800\text{ V}$ $T_j = 150^\circ\text{C}$	10	$\mu\text{s}$
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$



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## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Buck Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		650	V
Continuous (direct) forward current	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	55	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	150	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	71	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>Boost Switch</b>				
Collector-emitter voltage	$V_{CES}$		650	V
Collector current	$I_C$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	58	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	225	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	101	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ $V_{cc} = 360\text{ V}$ $T_j = 150^\circ\text{C}$	6	$\mu\text{s}$
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>Boost Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		1200	V
Continuous (direct) forward current	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	53	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	100	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	90	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$



## Maximum Ratings

$T_j = 25 \text{ } ^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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### Module Properties

#### Thermal Properties

Storage temperature	$T_{\text{stg}}$		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	$T_{\text{jop}}$		-40...( $T_{\text{jmax}} - 25$ )	$^\circ\text{C}$

#### Isolation Properties

Isolation voltage	$V_{\text{isol}}$	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance		Solder pin / Press-fit pin		9,15 / 8,95	mm
Comparative Tracking Index	CTI			> 200	

\*100 % tested in production



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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit	
		$V_{GE}$ [V]	$V_{CE}$ [V]	$I_c$ [A]	$I_D$ [A]	$T_j$ [°C]	$V_{GS}$ [V]	$V_{DS}$ [V]	$I_F$ [A]	Min	Typ	Max

### Buck Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(\text{th})}$	$V_{GE} = V_{CE}$			0,003	25		5,3	5,8	6,3	V
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$		15		80	125 150		1,78	1,99 2,33 2,41	2,42	V
Collector-emitter cut-off current	$I_{CES}$		0	1200		25				10	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25				240	nA
Internal gate resistance	$r_g$								none		Ω
Input capacitance	$C_{ies}$	$f = 1 \text{ Mhz}$	0	25	25	25			4660		pF
Output capacitance	$C_{oes}$								300		
Reverse transfer capacitance	$C_{res}$								260		
Gate charge	$Q_g$		15	960	80	25			370		nC

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						0,51		K/W
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#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 4 \Omega$ $R_{goff} = 4 \Omega$	$\pm 15$	350	50	25 125			77 79		ns
Rise time	$t_r$					25 125			11 14		
Turn-off delay time	$t_{d(off)}$					25 125			180 242		
Fall time	$t_f$	$Q_{rFWD} = 2,1 \mu\text{C}$ $Q_{fFWD} = 3,8 \mu\text{C}$	$\pm 15$	350	50	25 125			48 76		mWs
Turn-on energy (per pulse)	$E_{on}$					25 125			0,524 0,980		
Turn-off energy (per pulse)	$E_{off}$					25 125			1,31 2,28		



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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_c$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		

### Buck Diode

#### Static

Forward voltage	$V_F$				75	25 125 150		1,53 1,49 1,47	1,92		V
Reverse leakage current	$I_R$			650		25			3,8		µA

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,34		K/W
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#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt = 5245 \text{ A/}\mu\text{s}$ $di/dt = 3680 \text{ A/}\mu\text{s}$	$\pm 15$	350	50	25		63			A
Reverse recovery time	$t_{rr}$					125		73			
Recovered charge	$Q_r$					25		52			ns
Recovered charge	$Q_r$					125		92			
Reverse recovered energy	$E_{rec}$					25		2,06			µC
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		3,80			



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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit	
		$V_{GE}$ [V]	$V_{CE}$ [V]	$I_c$ [A]	$I_D$ [A]	$T_j$ [°C]	$V_{GS}$ [V]	$V_{DS}$ [V]	$I_F$ [A]	Min	Typ	Max

### Boost Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(\text{th})}$	$V_{GE} = V_{CE}$			0,0012	25		5,1	5,8	6,4	V
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$		15		75	25 125 150		0,93	1,46 1,55 1,76	1,77	V
Collector-emitter cut-off current	$I_{CES}$		0	650		25				3,8	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25				600	nA
Internal gate resistance	$r_g$							none			Ω
Input capacitance	$C_{ies}$	$f = 1 \text{ Mhz}$	0	25	25			4620			pF
Output capacitance	$C_{oes}$										
Reverse transfer capacitance	$C_{res}$										
Gate charge	$Q_g$		15	480	75	25			470		nC

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)							0,94		K/W
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#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 4 \Omega$ $R_{goff} = 4 \Omega$	$\pm 15$	350	56	25 125		84 85			ns
Rise time	$t_r$					25 125		11 12			
Turn-off delay time	$t_{d(off)}$					25 125		177 205			
Fall time	$t_f$	$Q_{rFWD} = 5,3 \mu\text{C}$ $Q_{rFWD} = 8,2 \mu\text{C}$				25 125		86 105			mWs
Turn-on energy (per pulse)	$E_{on}$					25 125		0,528 0,747			
Turn-off energy (per pulse)	$E_{off}$					25 125		1,86 2,50			



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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_c$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		

### Boost Diode

#### Static

Forward voltage	$V_F$				50	25 125 150		1,73 1,70 1,68	2,05	V
Reverse leakage current	$I_R$			1200		25			10	$\mu A$

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,06		K/W
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#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt = 6090 \text{ A}/\mu\text{s}$ $di/dt = 5325 \text{ A}/\mu\text{s}$	$\pm 15$	350	56	25 125		106 118		A
Reverse recovery time	$t_{rr}$					25 125		102 148		ns
Recovered charge	$Q_r$					25 125		5,32 8,22		$\mu C$
Reverse recovered energy	$E_{rec}$					25 125		1,55 2,42		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 125		6904 4951		$A/\mu s$

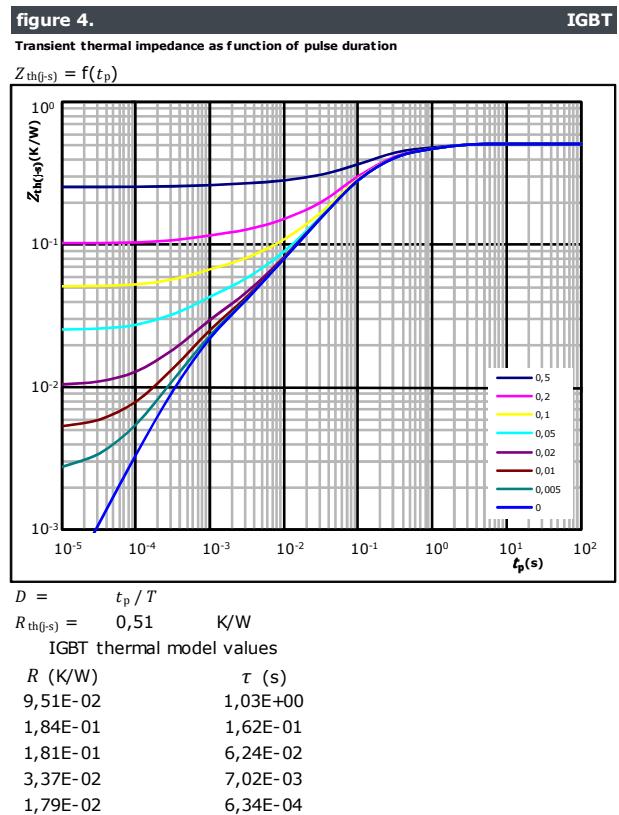
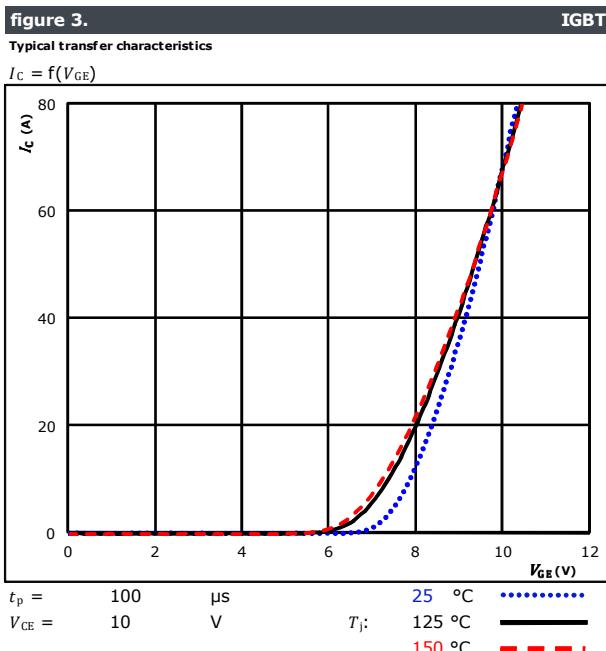
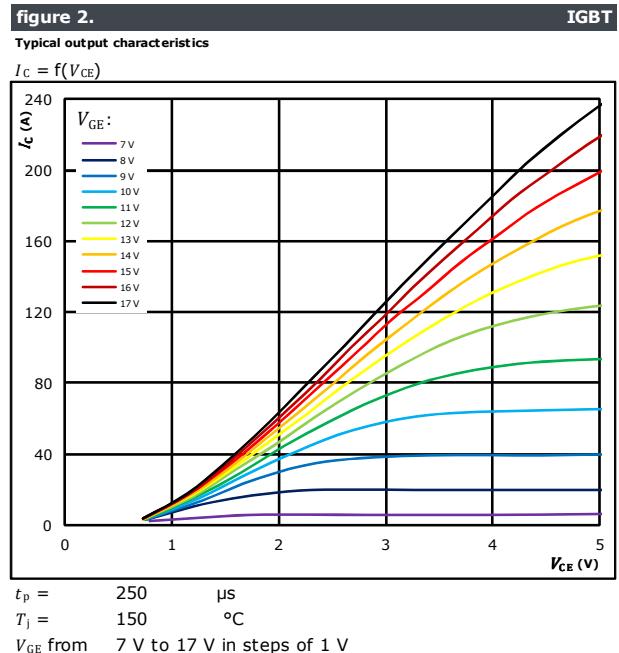
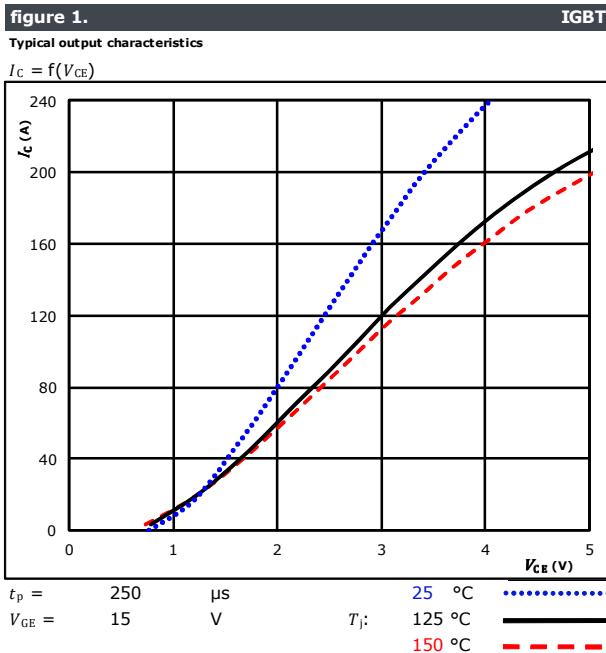
### Thermistor

Rated resistance	$R$					25		22		$k\Omega$
Deviation of $R_{100}$	$\Delta R/R$	$R_{100} = 1486 \Omega$				100	-12		+14	%
Power dissipation	$P$					25		200		mW
Power dissipation constant						25		2		$mW/K$
B-value	$B_{(25/50)}$	Tol. ±3%				25		3950		K
B-value	$B_{(25/100)}$	Tol. ±3%				25		3998		K
Vincotech NTC Reference								B		



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## Buck Switch Characteristics





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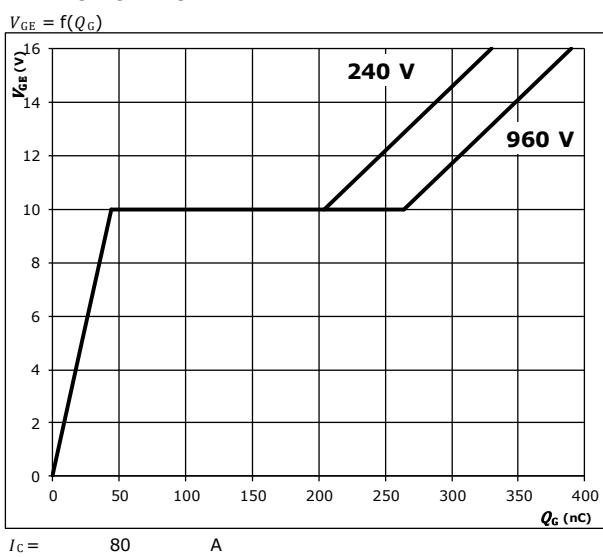
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## Buck Switch Characteristics

**figure 5.**

Gate voltage vs gate charge

**IGBT**

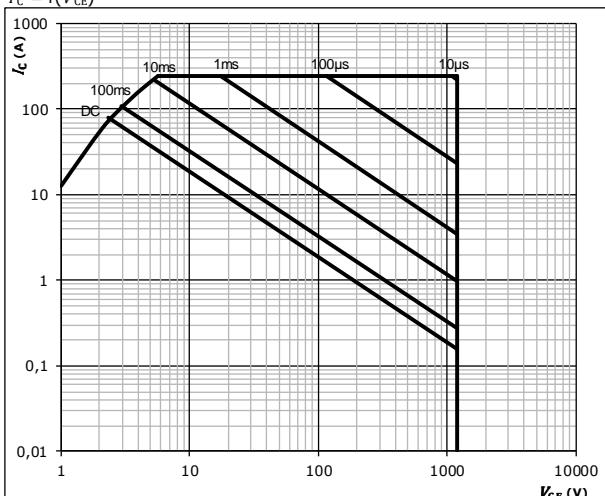


**figure 6.**

Safe operating area

$I_C = f(V_{CE})$

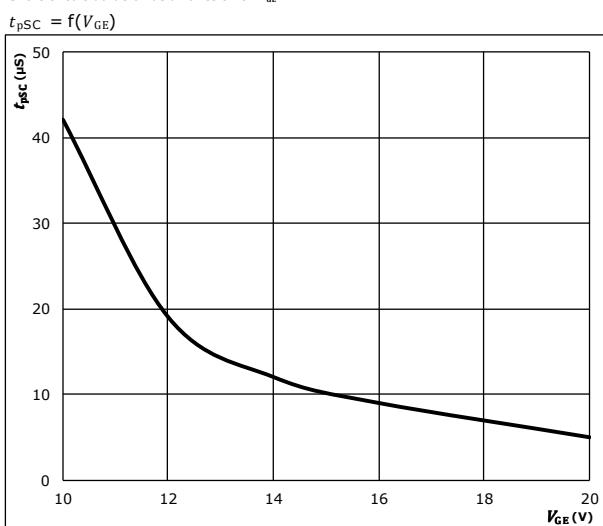
**IGBT**



**figure 7.**

Short circuit duration as a function of  $V_{GE}$

**IGBT**

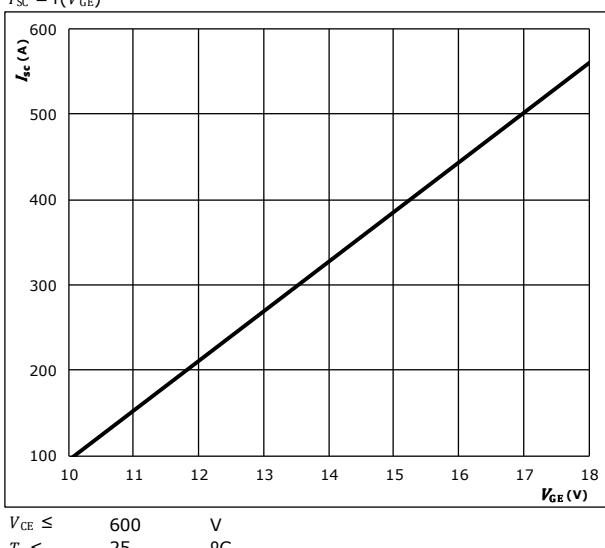


**figure 8.**

Typical short circuit current as a function of  $V_{GE}$

$I_{SC} = f(V_{GE})$

**IGBT**

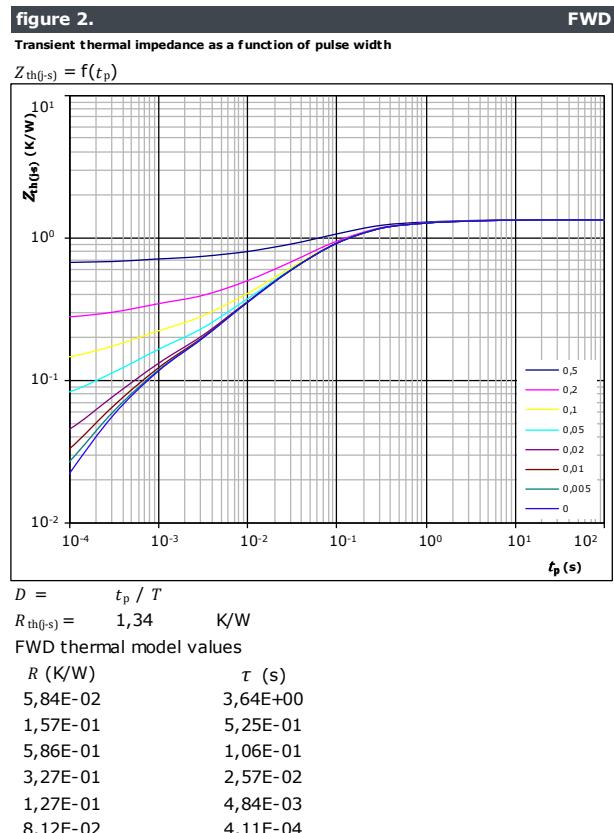
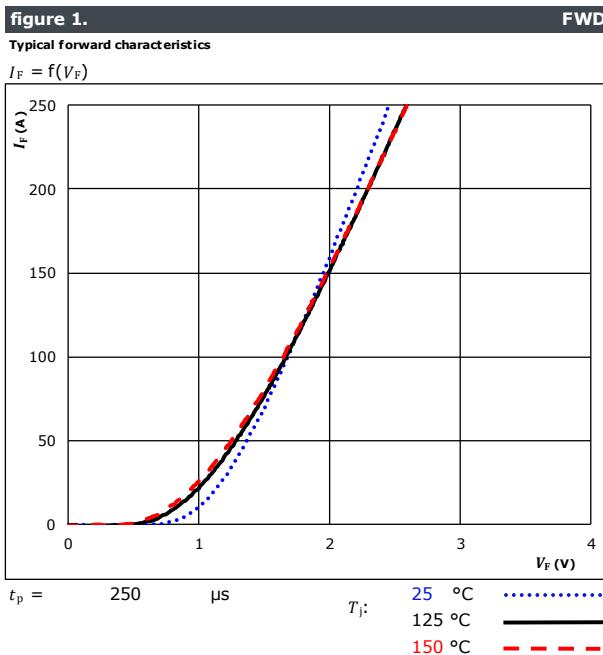




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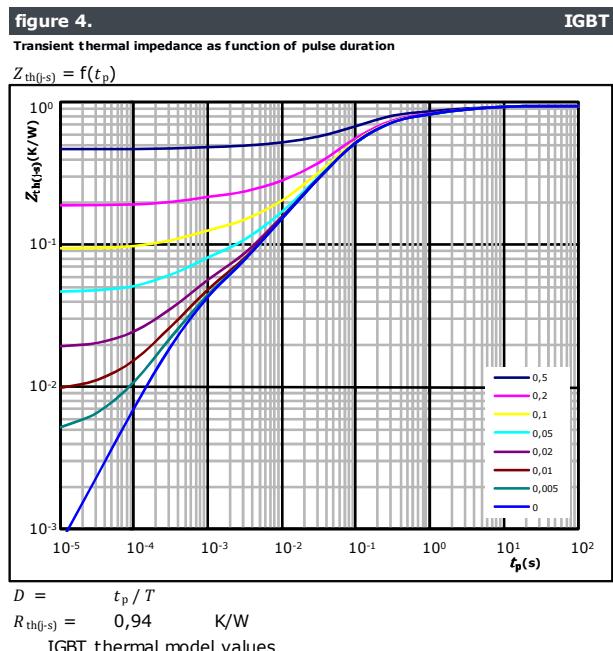
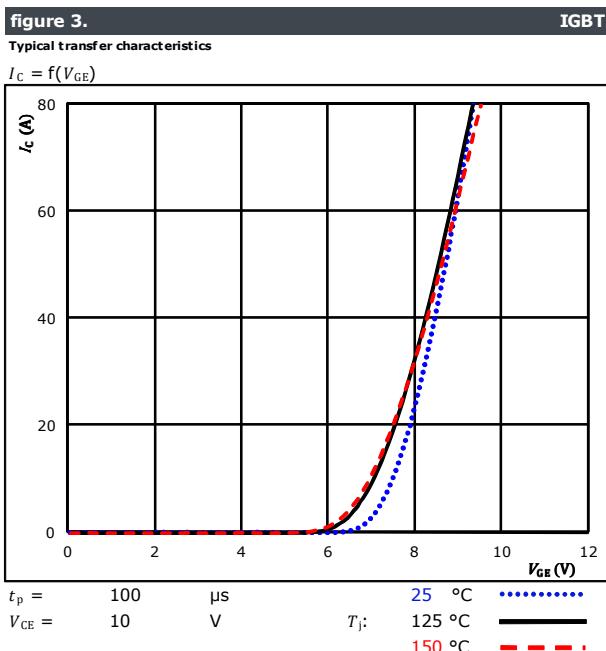
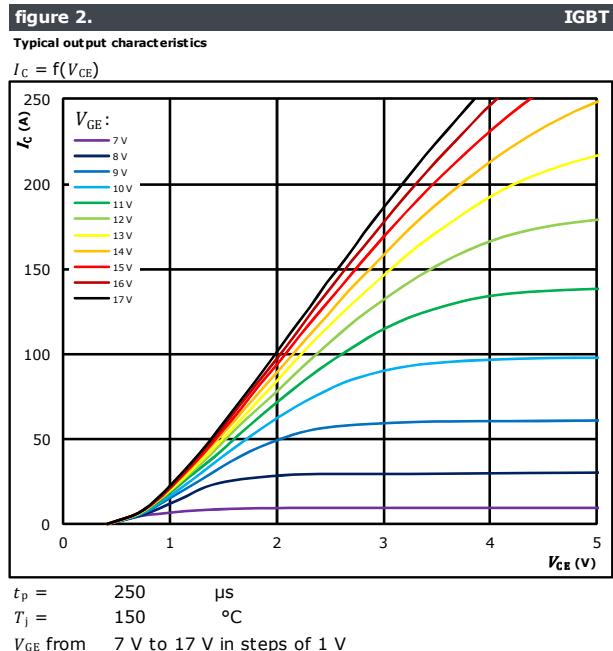
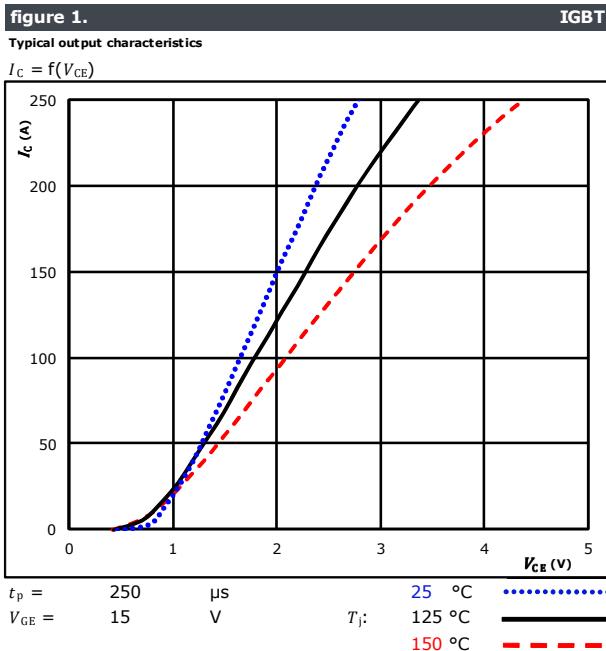
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datasheet

## Buck Diode Characteristics





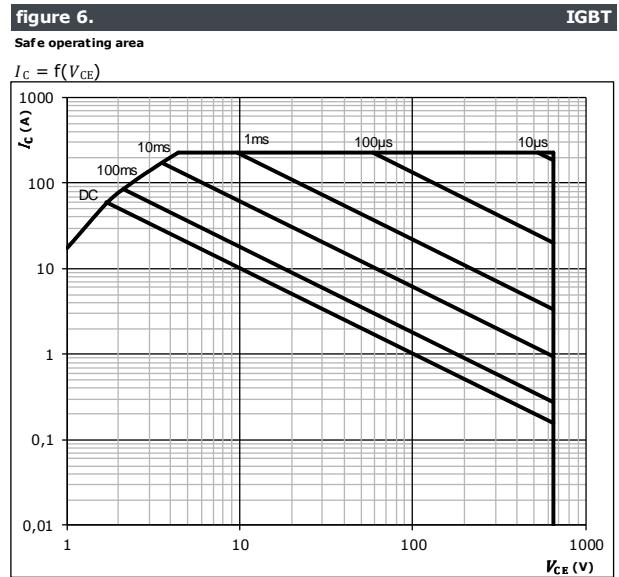
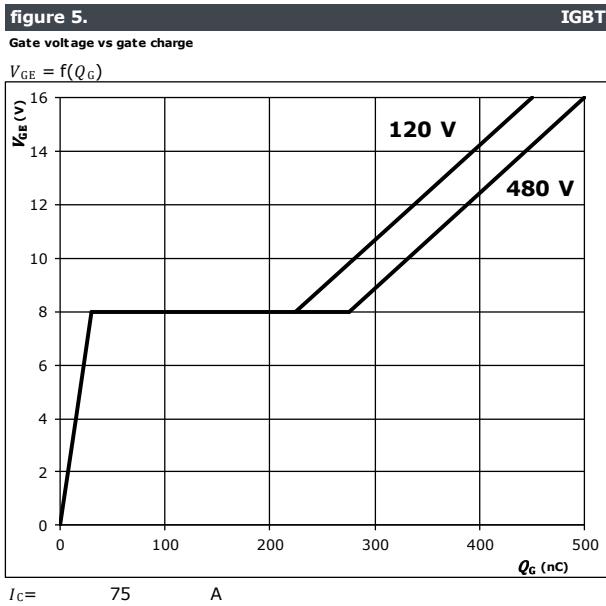
## Boost Switch Characteristics



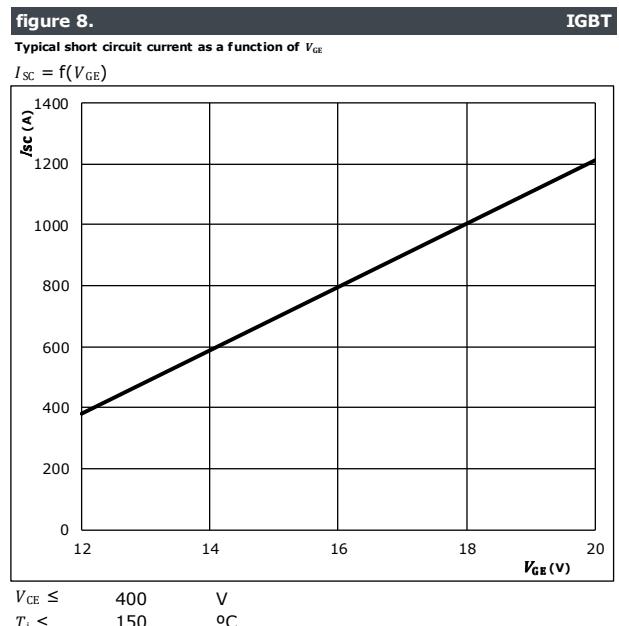
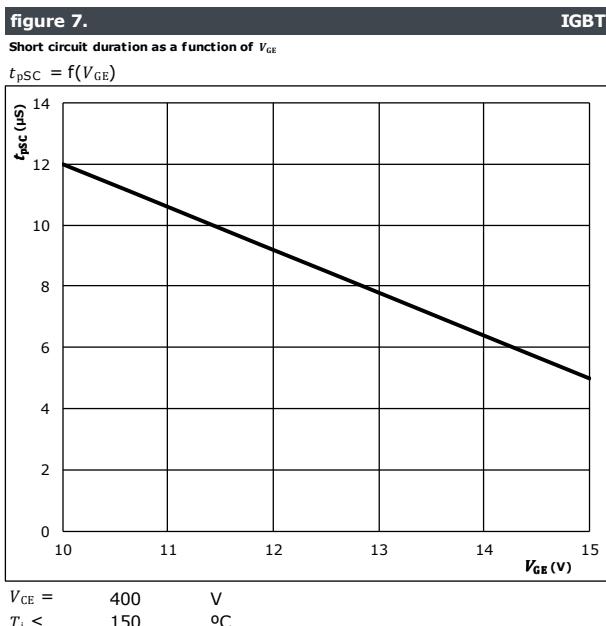


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## Boost Switch Characteristics



$D$  = single pulse  
 $T_s$  = 80 °C  
 $V_{GE}$  = ±15 V  
 $T_j$  =  $T_{jmax}$  °C

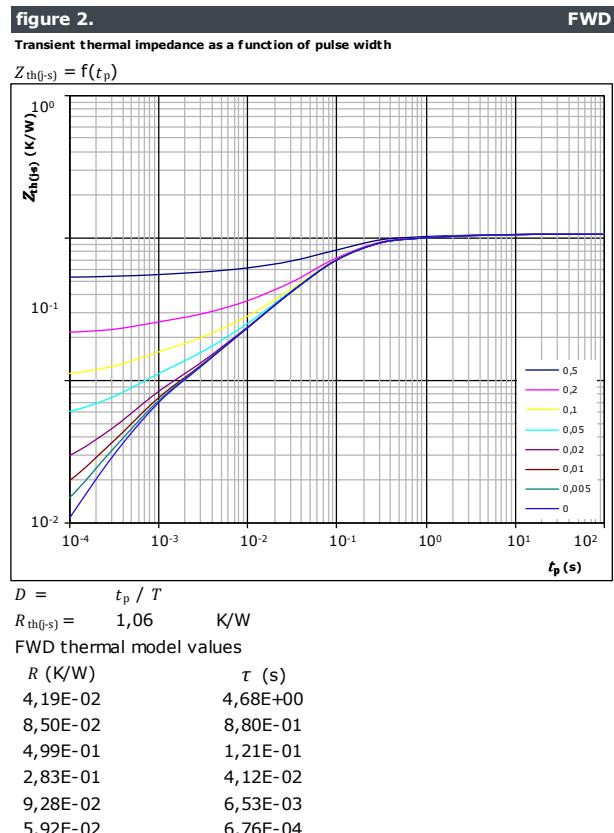
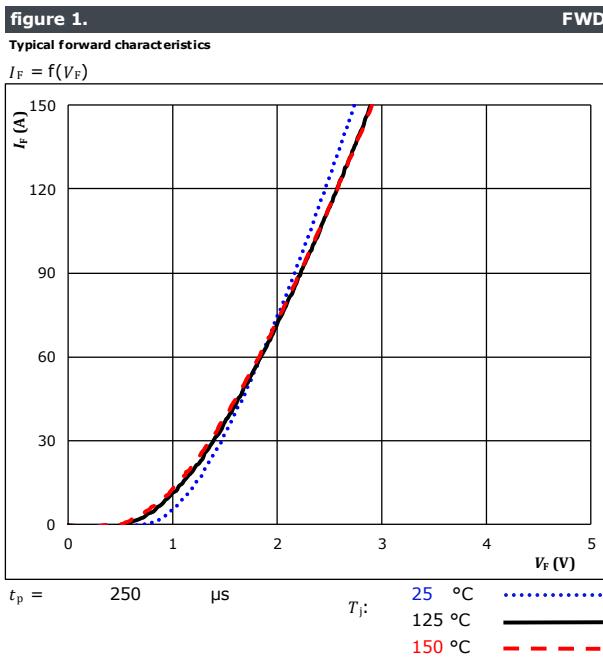




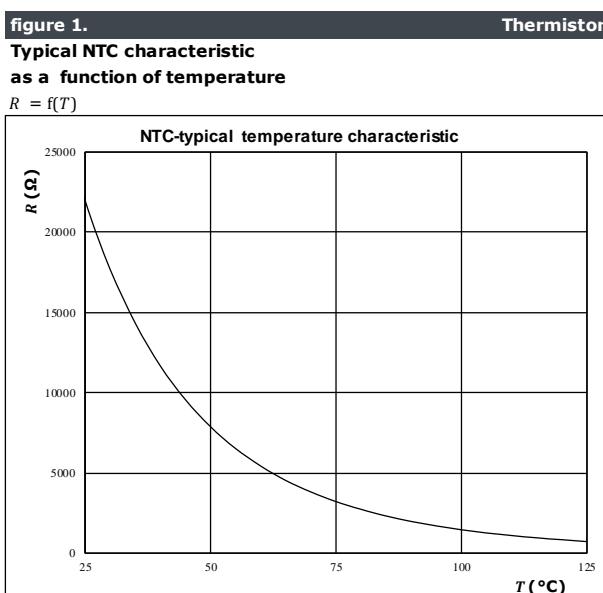
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## Boost Diode Characteristics



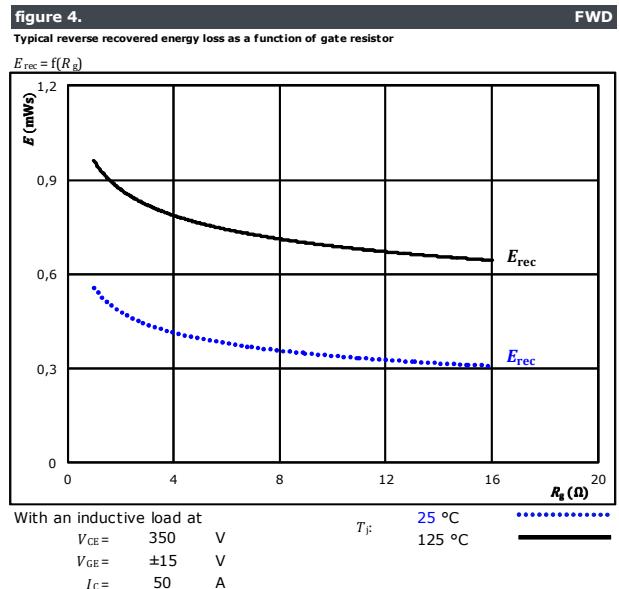
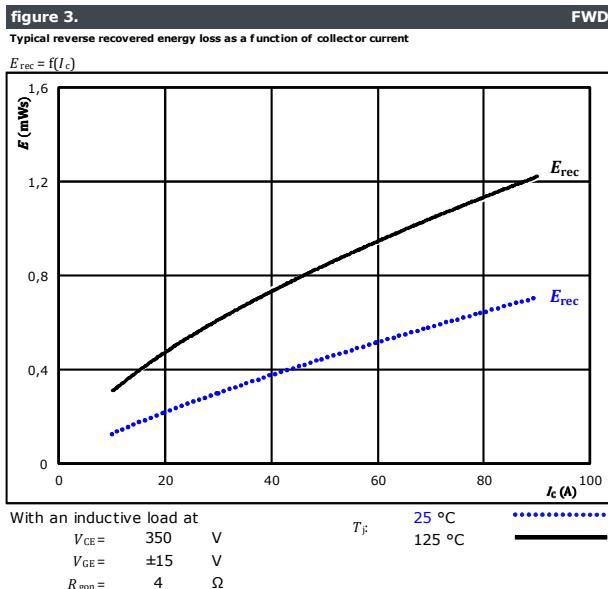
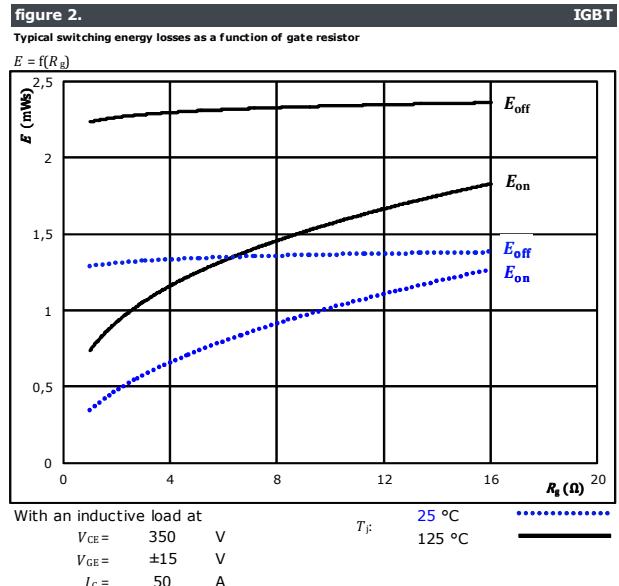
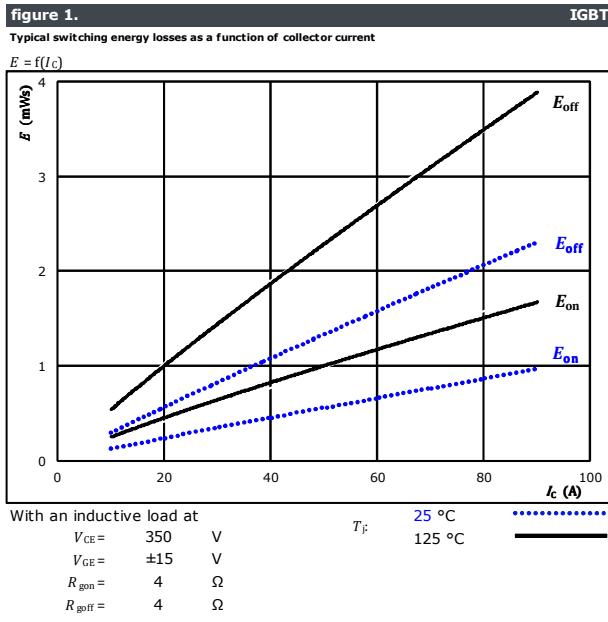
## Thermistor Characteristics





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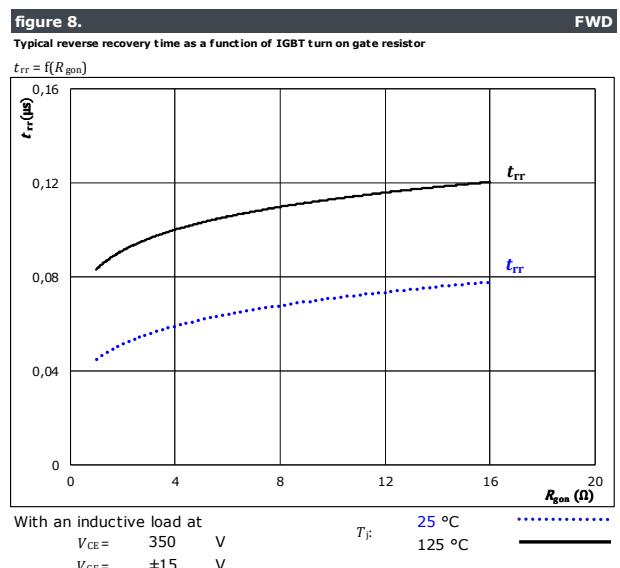
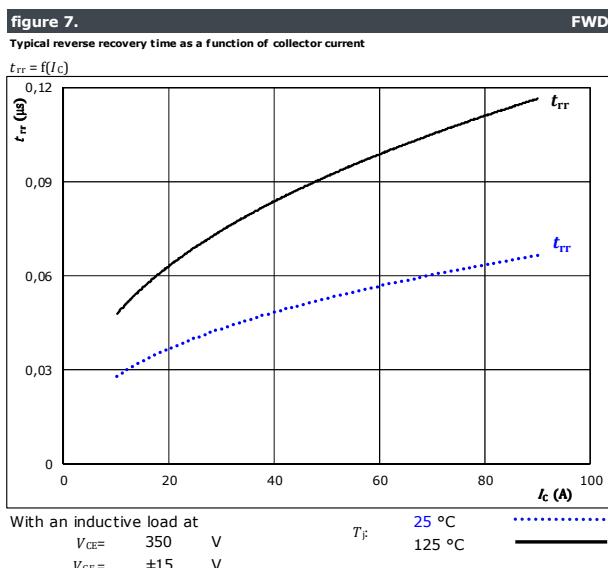
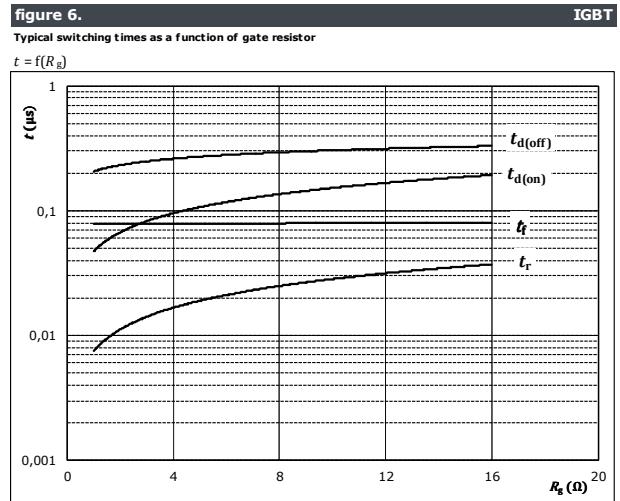
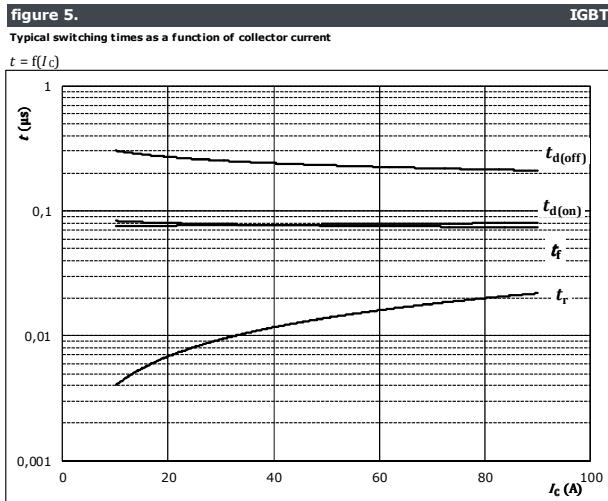
## Buck Switching Characteristics





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## Buck Switching Characteristics



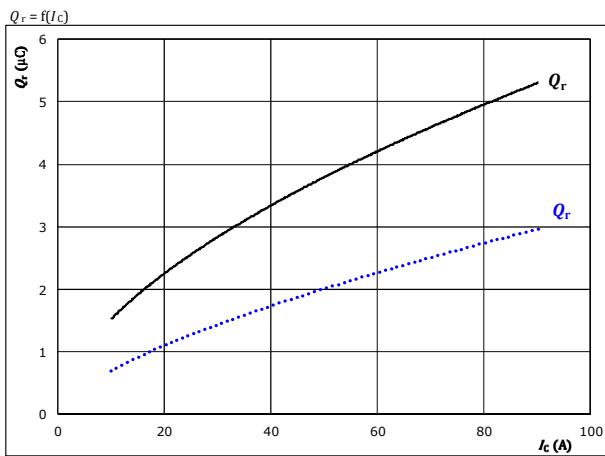


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## Buck Switching Characteristics

figure 9.

Typical recovered charge as a function of collector current

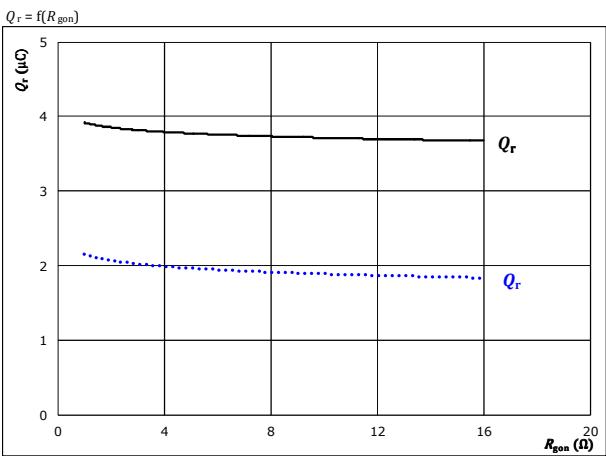


With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $R_{gon} = 4$  Ω  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

FWD

figure 10.

Typical recovered charge as a function of IGBT turn on gate resistor

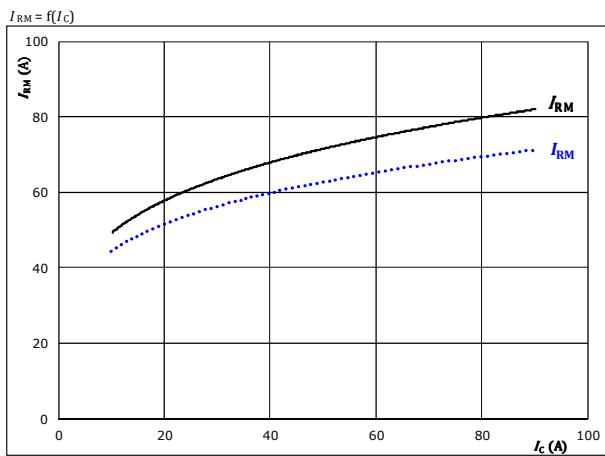


With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $I_C = 50$  A  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

FWD

figure 11.

Typical peak reverse recovery current as a function of collector current

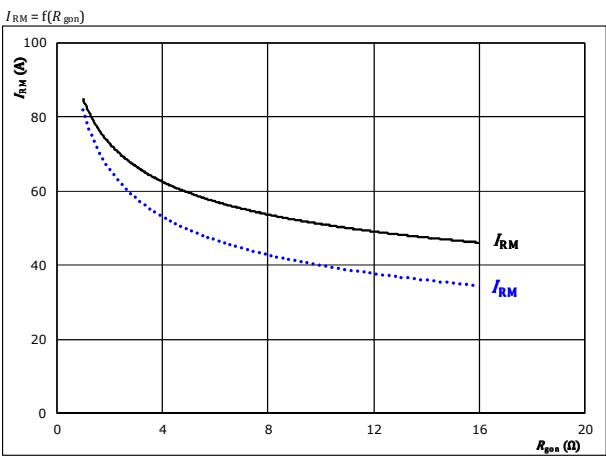


With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $R_{gon} = 4$  Ω  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

FWD

figure 12.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor



With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $I_C = 50$  A  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C



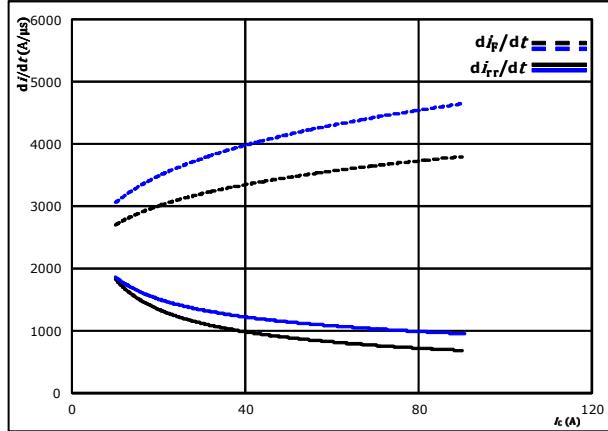
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## Buck Switching Characteristics

**figure 13.**

Typical rate of fall of forward and reverse recovery current as a function of collector current

$$di_F/dt, di_{rr}/dt = f(I_C)$$



With an inductive load at

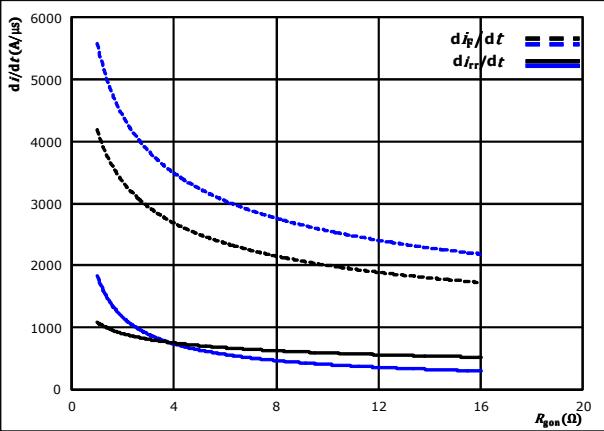
$$\begin{aligned} V_{CE} &= 350 \text{ V} & T_F &= 25^\circ\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 4 \Omega & & \end{aligned}$$

**FWD**

**figure 14.**

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$$di_F/dt, di_{rr}/dt = f(R_{gon})$$



With an inductive load at

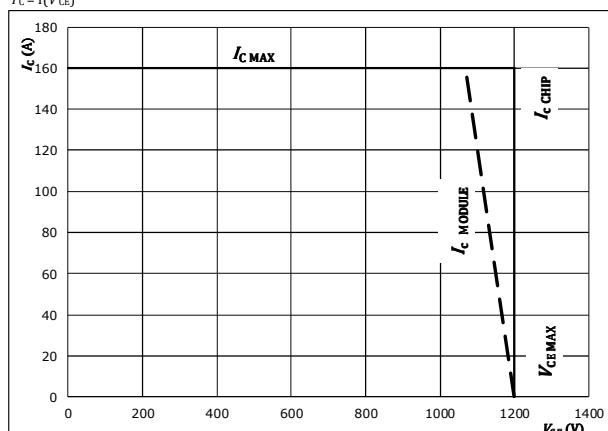
$$\begin{aligned} V_{CE} &= 350 \text{ V} & T_F &= 25^\circ\text{C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_C &= 50 \text{ A} & 125^\circ\text{C} & \end{aligned}$$

**FWD**

**figure 15.**

Reverse bias safe operating area

$$I_C = f(V_{CE})$$



At

$$\begin{aligned} T_J &= 125^\circ\text{C} \\ R_{gon} &= 4 \Omega \\ R_{goff} &= 4 \Omega \end{aligned}$$



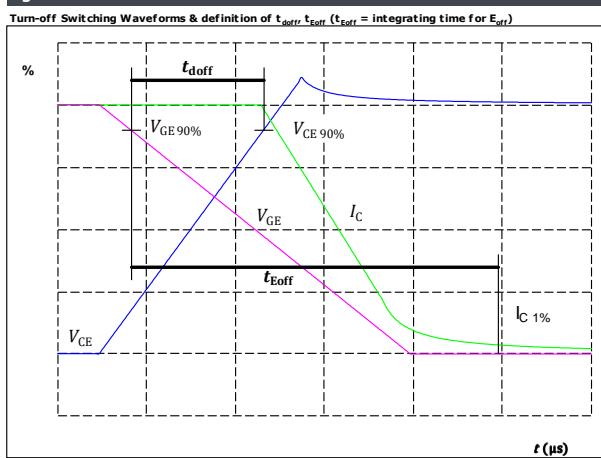
## Buck Switching Definitions

### General conditions

$T_j$	=	125 °C
$R_{gon}$	=	4 Ω
$R_{goff}$	=	4 Ω

figure 1.

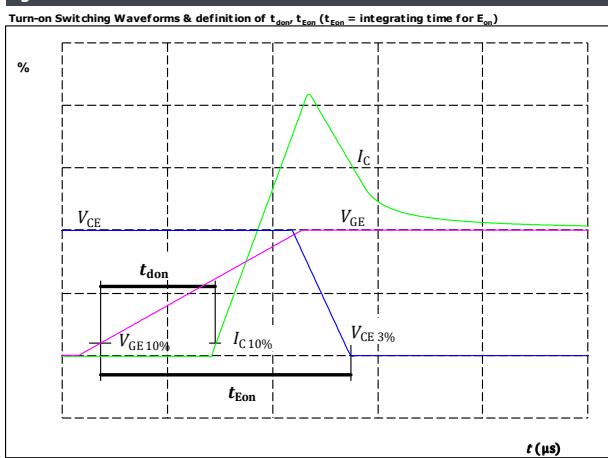
IGBT



$V_{GE}(0\%) = -15$  V  
 $V_{GE}(100\%) = 15$  V  
 $V_C(100\%) = 350$  V  
 $I_C(100\%) = 50$  A  
 $t_{doff} = 242$  ns

figure 2.

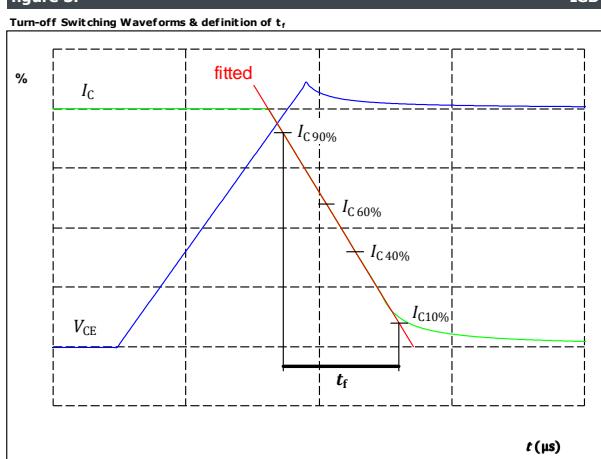
IGBT



$V_{GE}(0\%) = -15$  V  
 $V_{GE}(100\%) = 15$  V  
 $V_C(100\%) = 350$  V  
 $I_C(100\%) = 50$  A  
 $t_{don} = 79$  ns

figure 3.

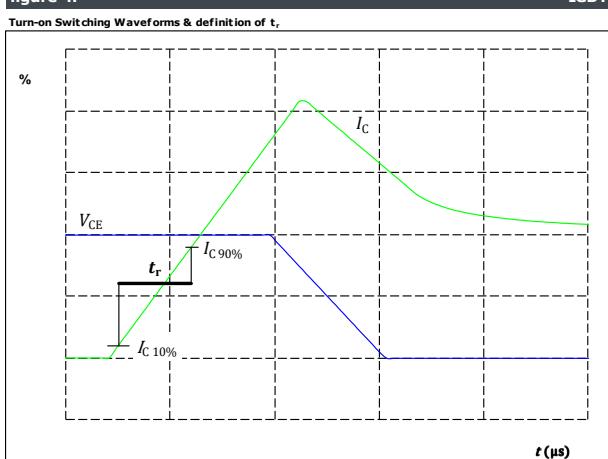
IGBT



$V_C(100\%) = 350$  V  
 $I_C(100\%) = 50$  A  
 $t_f = 76$  ns

figure 4.

IGBT



$V_C(100\%) = 350$  V  
 $I_C(100\%) = 50$  A  
 $t_r = 14$  ns



**10-FZ12NMA080SH04-M260F13**  
**10-PZ12NMA080SH04-M260F13Y**  
datasheet

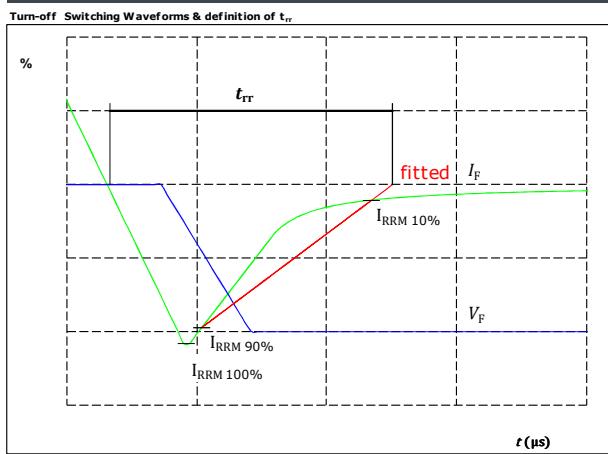
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## Buck Switching Characteristics

figure 5.

Turn-off Switching Waveforms & definition of  $t_{rr}$

FWD

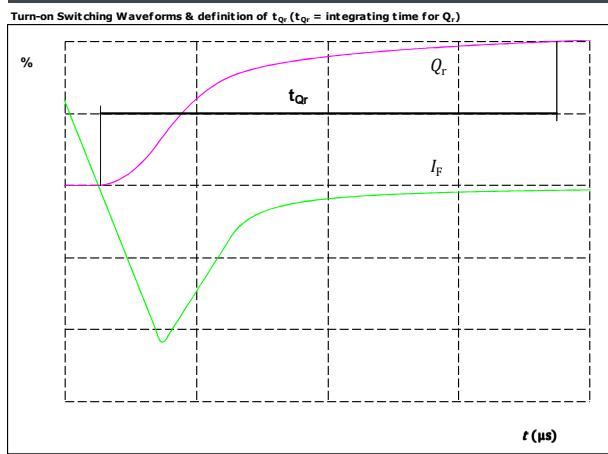


$V_F(100\%) = 350 \text{ V}$   
 $I_F(100\%) = 50 \text{ A}$   
 $I_{RRM}(100\%) = 73 \text{ A}$   
 $t_{rr} = 92 \text{ ns}$

figure 6.

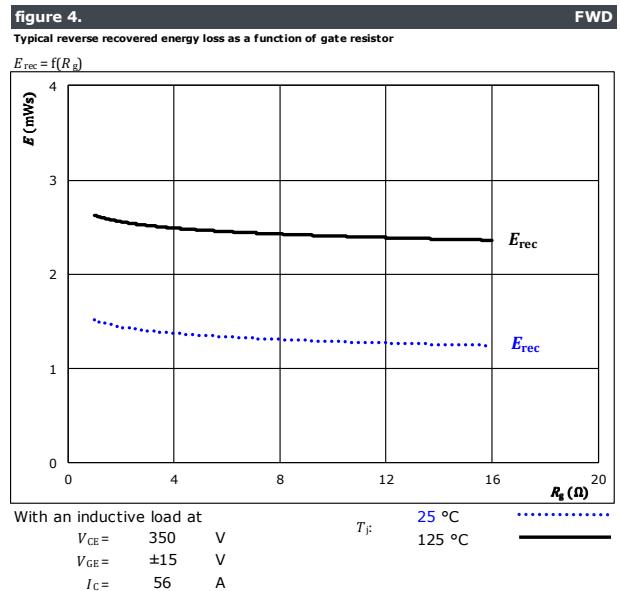
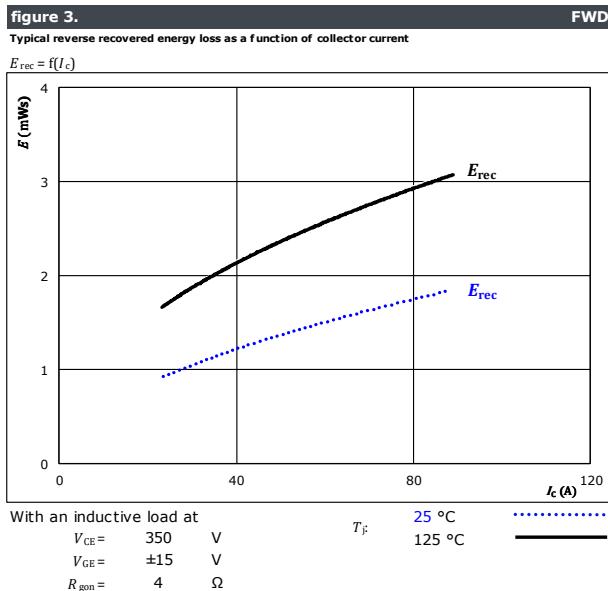
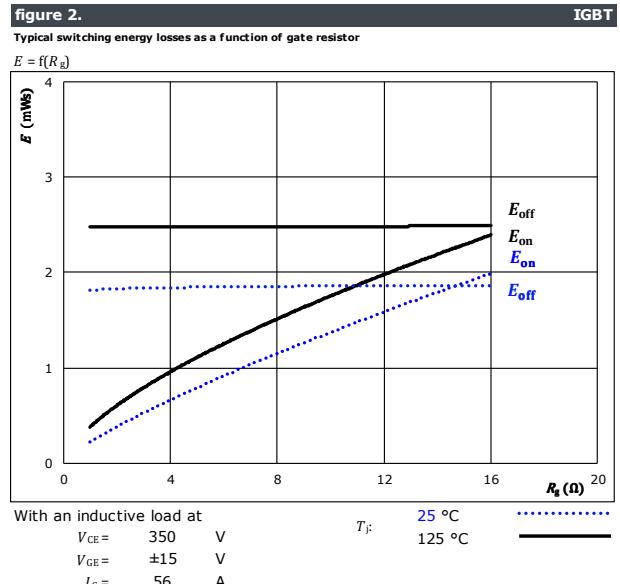
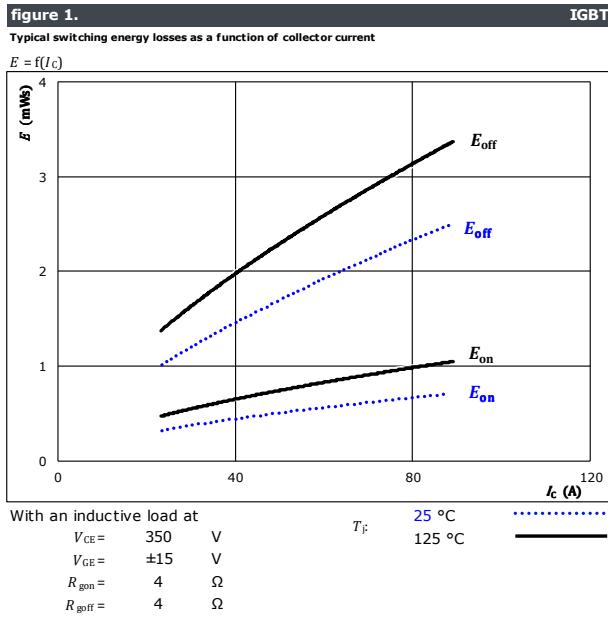
Turn-on Switching Waveforms & definition of  $t_{qr}$  ( $t_{qr}$  = integrating time for  $Q_r$ )

FWD





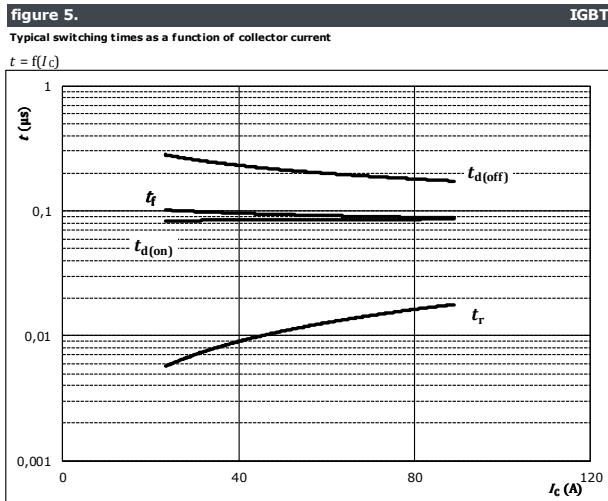
## Boost Switching Characteristics





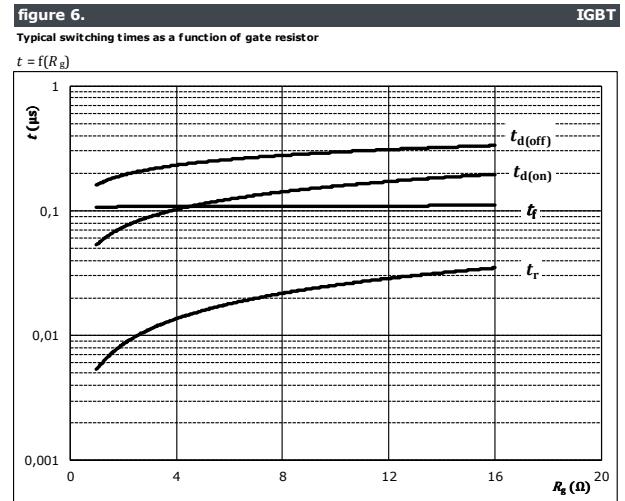
Vincotech

## Boost Switching Characteristics



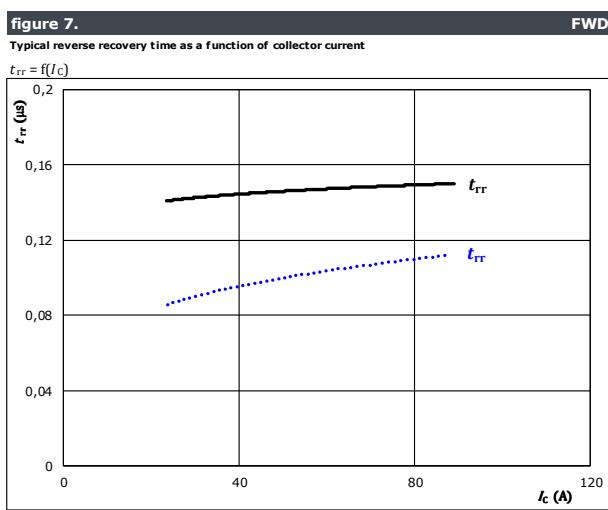
With an inductive load at

$T_J = 0 \text{ } ^\circ\text{C}$   
 $V_{CE} = 350 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 4 \Omega$   
 $R_{goff} = 4 \Omega$



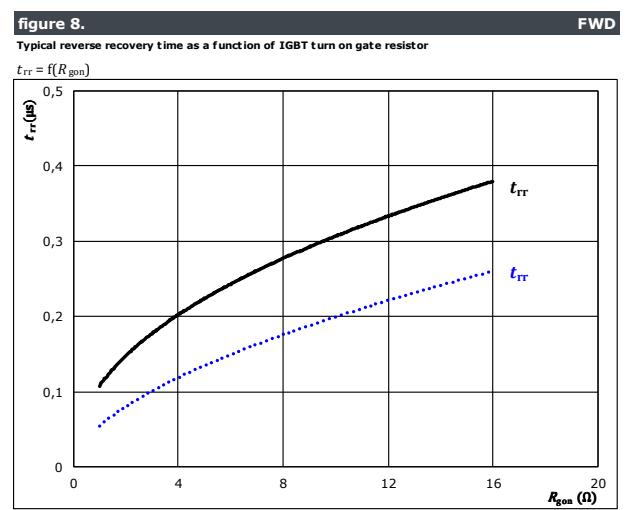
With an inductive load at

$T_J = 0 \text{ } ^\circ\text{C}$   
 $V_{CE} = 350 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 56 \text{ A}$



With an inductive load at

$V_{CE} = 350 \text{ V}$   $T_f: 25 \text{ } ^\circ\text{C} \text{ (solid)}$   $125 \text{ } ^\circ\text{C} \text{ (dotted)}$



With an inductive load at

$V_{CE} = 350 \text{ V}$   $T_f: 25 \text{ } ^\circ\text{C} \text{ (solid)}$   $125 \text{ } ^\circ\text{C} \text{ (dotted)}$

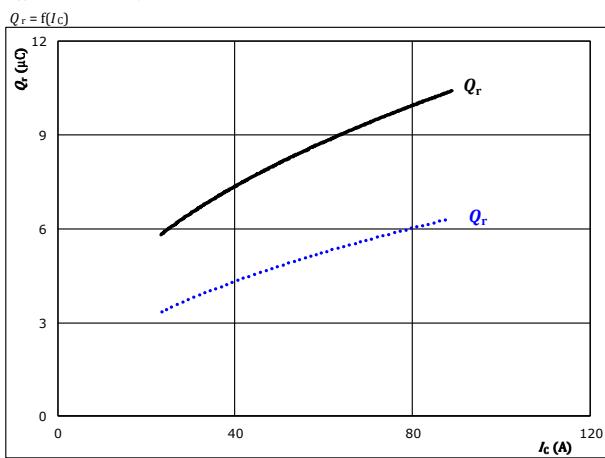


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## Boost Switching Characteristics

figure 9.

Typical recovered charge as a function of collector current

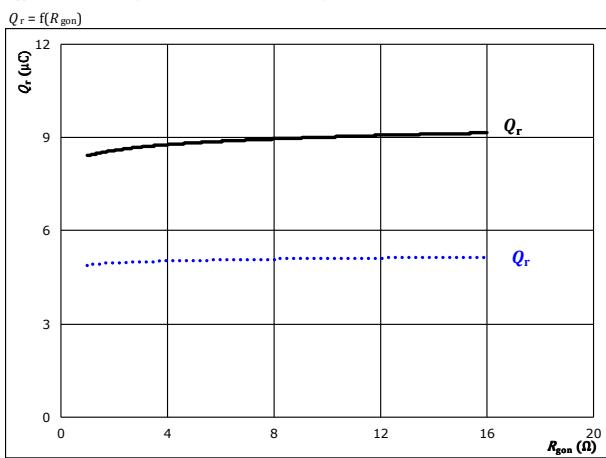


With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $R_{gon} = 4$  Ω  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

FWD

figure 10.

Typical recovered charge as a function of IGBT turn on gate resistor

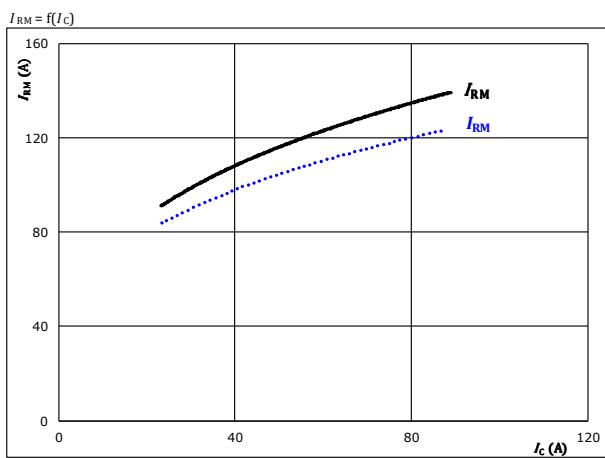


With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $I_c = 56$  A  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

FWD

figure 11.

Typical peak reverse recovery current as a function of collector current

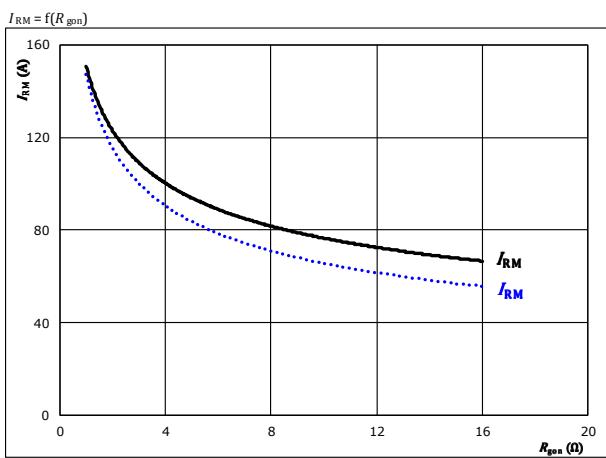


With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $R_{gon} = 4$  Ω  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

FWD

figure 12.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor



With an inductive load at  
 $V_{CE} = 350$  V       $T_f = 25$  °C       $I_c = 56$  A  
 $V_{GE} = \pm 15$  V       $T_f = 125$  °C

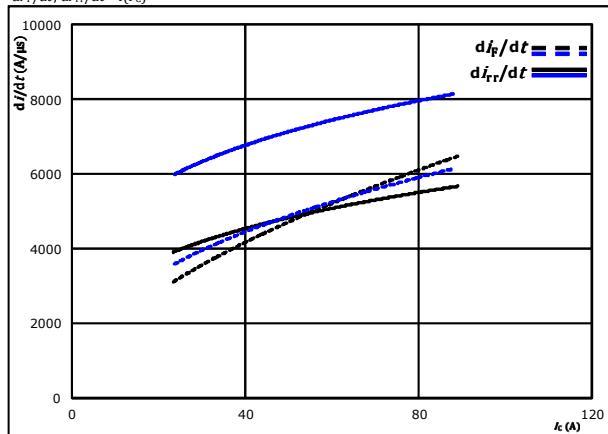


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## Boost Switching Characteristics

**figure 13.**

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_F/dt, di_{rr}/dt = f(I_C)$

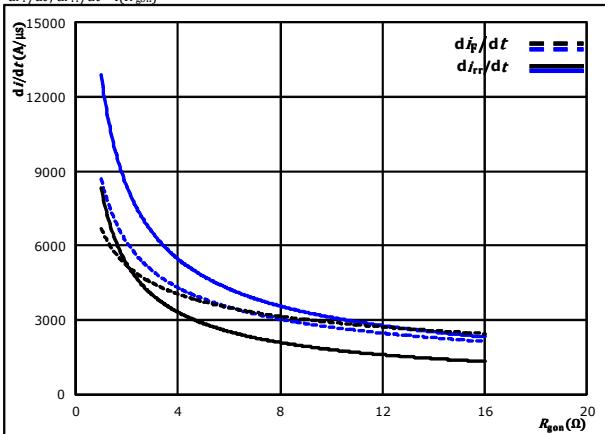


With an inductive load at  
 $V_{CE} = 350$  V       $T_F = 25$  °C  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$  Ω

**FWD**

**figure 14.**

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor  
 $di_F/dt, di_{rr}/dt = f(R_{gon})$

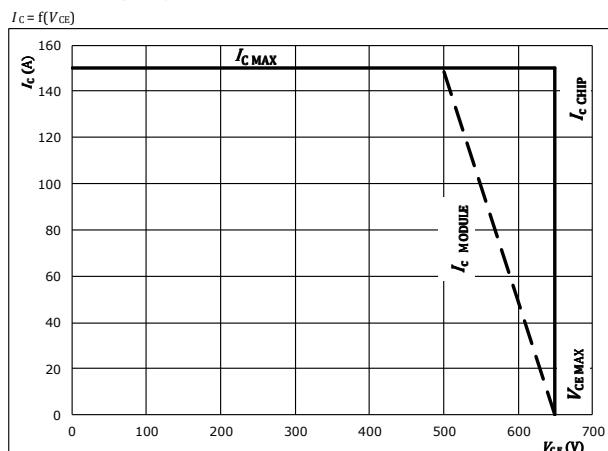


With an inductive load at  
 $V_{CE} = 350$  V       $T_F = 25$  °C  
 $V_{GE} = \pm 15$  V  
 $I_C = 56$  A

**FWD**

**figure 15.**

Reverse bias safe operating area  
 $I_C = f(V_{CE})$



At

$T_J = 125$  °C  
 $R_{gon} = 4$  Ω  
 $R_{goff} = 4$  Ω

**IGBT**



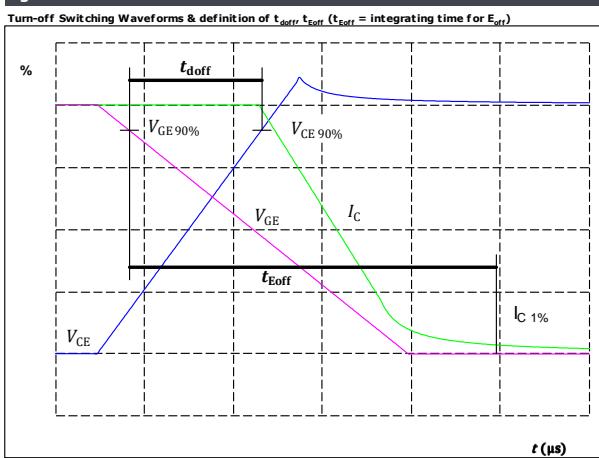
## Boost Switching Definitions

### General conditions

$T_j$	=	125 °C
$R_{gon}$	=	4 Ω
$R_{goff}$	=	4 Ω

figure 1.

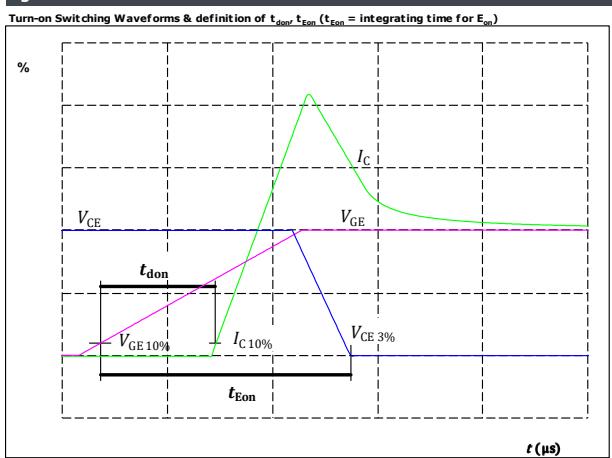
IGBT



$V_{GE}(0\%) = -15$  V  
 $V_{GE}(100\%) = 15$  V  
 $V_C(100\%) = 350$  V  
 $I_C(100\%) = 56$  A  
 $t_{doff} = 205$  ns

figure 2.

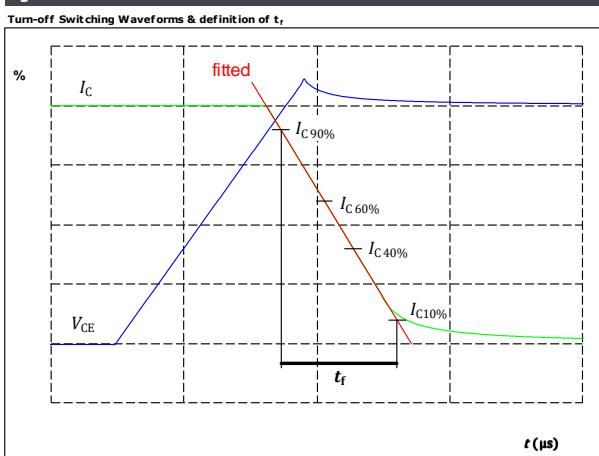
IGBT



$V_{GE}(0\%) = -15$  V  
 $V_{GE}(100\%) = 15$  V  
 $V_C(100\%) = 350$  V  
 $I_C(100\%) = 56$  A  
 $t_{don} = 85$  ns

figure 3.

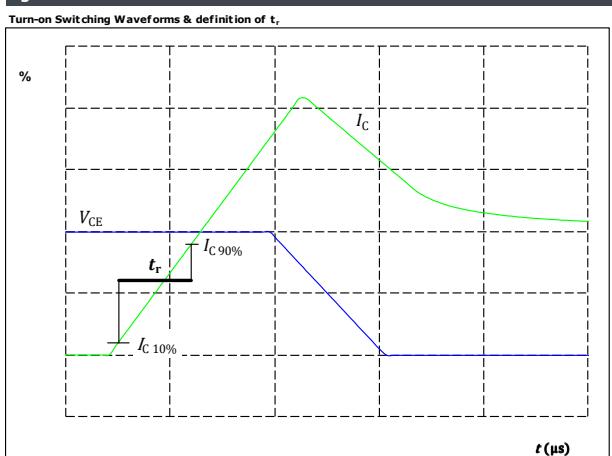
IGBT



$V_C(100\%) = 350$  V  
 $I_C(100\%) = 56$  A  
 $t_f = 105$  ns

figure 4.

IGBT



$V_C(100\%) = 350$  V  
 $I_C(100\%) = 56$  A  
 $t_r = 12$  ns



**10-FZ12NMA080SH04-M260F13**  
**10-PZ12NMA080SH04-M260F13Y**  
datasheet

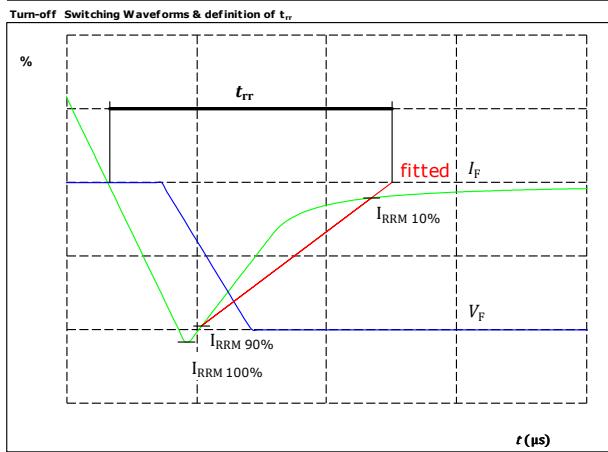
Vincotech

## Boost Switching Characteristics

figure 5.

Turn-off Switching Waveforms & definition of  $t_{rr}$

FWD

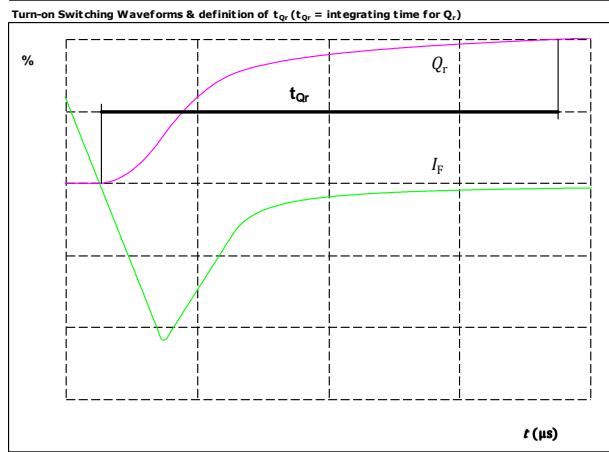


$V_F(100\%) = 350 \text{ V}$   
 $I_F(100\%) = 56 \text{ A}$   
 $I_{RRM}(100\%) = 118 \text{ A}$   
 $t_{rr} = 148 \text{ ns}$

figure 6.

Turn-on Switching Waveforms & definition of  $t_{qr}$  ( $t_{qr}$  = integrating time for  $Q_r$ )

FWD



$I_F(100\%) = 56 \text{ A}$   
 $Q_r(100\%) = 8,22 \mu\text{C}$



**10-FZ12NMA080SH04-M260F13**  
**10-PZ12NMA080SH04-M260F13Y**  
datasheet

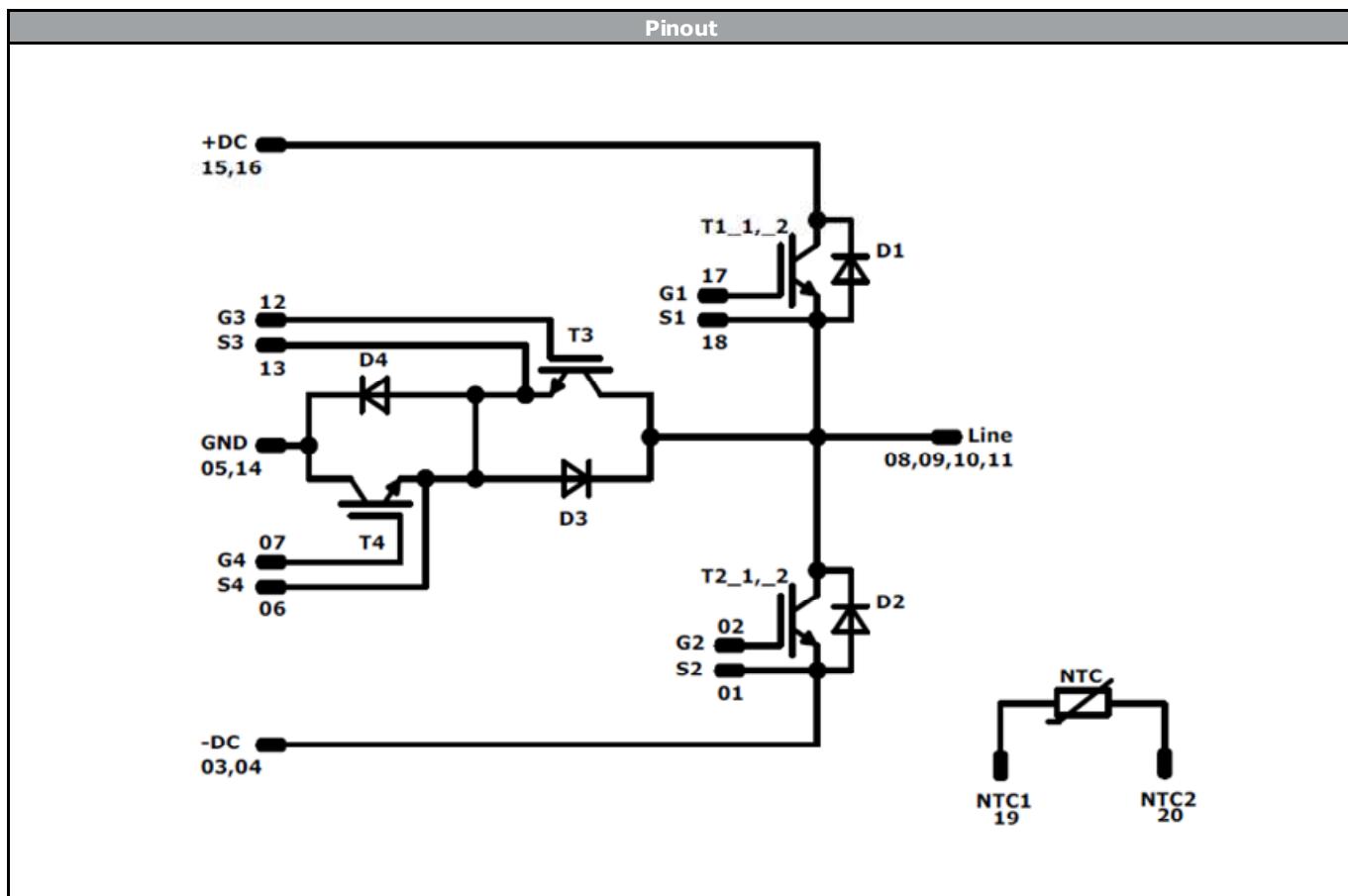
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Ordering Code & Marking																																																																																																			
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<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>33,6</td><td>0</td><td>S2</td></tr><tr><td>2</td><td>30,8</td><td>0</td><td>G2</td></tr><tr><td>3</td><td>22</td><td>0</td><td>-DC</td></tr><tr><td>4</td><td>19,2</td><td>0</td><td>-DC</td></tr><tr><td>5</td><td>10,1</td><td>0</td><td>GND</td></tr><tr><td>6</td><td>2,8</td><td>0</td><td>S4</td></tr><tr><td>7</td><td>0</td><td>0</td><td>G4</td></tr><tr><td>8</td><td>0</td><td>7,1</td><td>Line</td></tr><tr><td>9</td><td>0</td><td>9,9</td><td>Line</td></tr><tr><td>10</td><td>0</td><td>12,7</td><td>Line</td></tr><tr><td>11</td><td>0</td><td>15,5</td><td>Line</td></tr><tr><td>12</td><td>0</td><td>22,6</td><td>G3</td></tr><tr><td>13</td><td>2,8</td><td>22,6</td><td>S3</td></tr><tr><td>14</td><td>10,1</td><td>22,6</td><td>GND</td></tr><tr><td>15</td><td>19,2</td><td>22,6</td><td>+DC</td></tr><tr><td>16</td><td>22</td><td>22,6</td><td>+DC</td></tr><tr><td>17</td><td>30,8</td><td>22,6</td><td>G1</td></tr><tr><td>18</td><td>33,6</td><td>22,6</td><td>S1</td></tr><tr><td>19</td><td>33,6</td><td>14,8</td><td>NTC1</td></tr><tr><td>20</td><td>33,6</td><td>8,2</td><td>NTC2</td></tr><tr><td>21</td><td colspan="2">Not assembled</td><td></td></tr><tr><td>22</td><td colspan="2" rowspan="2">Not assembled</td><td></td></tr></tbody></table>		Pin	X		Y	Function	1	33,6	0	S2	2	30,8	0	G2	3	22	0	-DC	4	19,2	0	-DC	5	10,1	0	GND	6	2,8	0	S4	7	0	0	G4	8	0	7,1	Line	9	0	9,9	Line	10	0	12,7	Line	11	0	15,5	Line	12	0	22,6	G3	13	2,8	22,6	S3	14	10,1	22,6	GND	15	19,2	22,6	+DC	16	22	22,6	+DC	17	30,8	22,6	G1	18	33,6	22,6	S1	19	33,6	14,8	NTC1	20	33,6	8,2	NTC2	21	Not assembled			22	Not assembled							
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Tolerance of pinpositions +/-0.5mm at the end of pins Dimension of coordinate axis is only offset without tolerance																																																																																																			



**10-FZ12NMA080SH04-M260F13**  
**10-PZ12NMA080SH04-M260F13Y**  
datasheet

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Identification					
ID	Component	Voltage	Current	Function	Comment
T1, T2	IGBT	1200 V	80 A	Buck Switch	
D3, D4	FWD	650 V	75 A	Buck Diode	
T3, T4	IGBT	650 V	75 A	Boost Switch	
D1, D2	FWD	1200 V	50 A	Boost Diode	
NTC	NTC			Thermistor	



**10-FZ12NMA080SH04-M260F13  
10-PZ12NMA080SH04-M260F13Y**  
datasheet

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<b>Packaging instruction</b>			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

<b>Handling instruction</b>			
Handling instructions for flow 0 packages see vincotech.com website.			

<b>Package data</b>			
Package data for flow 0 packages see vincotech.com website.			

<b>UL recognition and file number</b>			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

<b>Document No.:</b>	<b>Date:</b>	<b>Modification:</b>	<b>Pages</b>
10-xZ12NMA080SH04-M260F13x-D1-14	12 Jun. 2018		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.